



BZT52HC2V4WF - BZT52HC47WF

SURFACE MOUNT ZENER DIODE

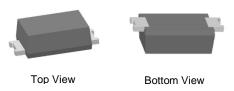
Features

- Flat Lead Package Design for Low Profile and High Power
 Dissipation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOD123F (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Band
- Terminals: Finish Matte Tin Annealed over Copper Alloy Leadframe. Solderable per MIL-STD-202, Method 208 ^(C)
- Polarity: Cathode Band
- Weight: 0.015 grams (Approximate)

SOD123F (Type B)



Ordering Information (Note 4)

1				
	Part Number	Compliance	Case	Packaging
	(Type Number)-7*	AEC-Q101	SOD123F (Type B)	3,000/Tape & Reel

*Add "-7" to the appropriate type number in Electrical Characteristics Table, example: 6.2V Zener = BZT52HC6V2WF-7.

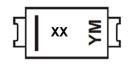
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



XX = Product Type Marking Code (See Electrical Characteristics Table) YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code K	ley											
Year Code		201	5	2016	2017		2018 2019		2020		2021	
		C		D	I	E			G	Н		I
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Forward Voltage (Note 5)	@ I _F = 10mA	VF	0.9	V
Forward Current		lF	250	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	375	mW
Power Dissipation (Note 7)	PD	830	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	R _{0JA}	330	°C/W
Thermal Resistance, Junction to Ambient Air (Note 7)	R _{0JA}	150	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	°C

Note:

 Short duration pulse test used to minimize self-heating effect.
 Device mounted on FR-4 PCB with minimum recommended pad layout, as shown in Diodes Incorporated's Suggested Pad Layout document, which can be found on our website at http://www.diodes.com/package-outlines.html. 7. Device mounted on FR-4 PCB with mounting pad for cathode 1cm².



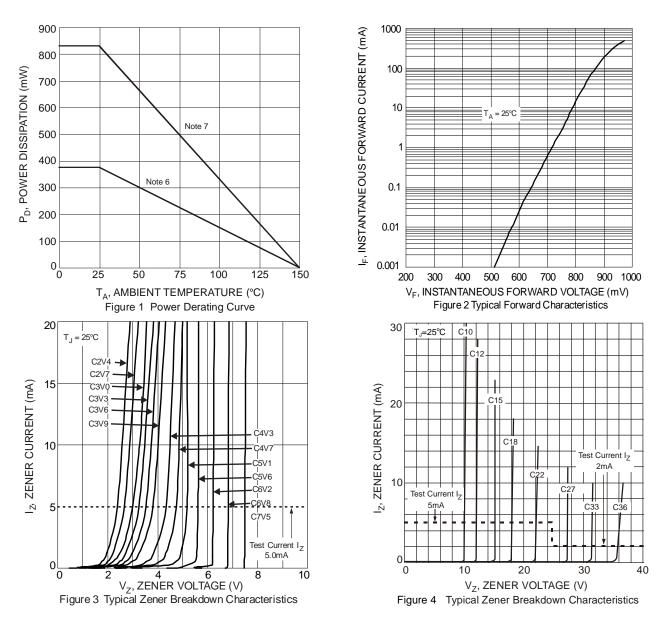
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

			ner Vo Rang (Note	e	Maximu	m Zener Im (Note 9)	pedance Temperature Coefficient		Total Capacitance	Maximum Reverse Current (Note 8)		
Type Number	Marking Codes	Vz @	₿ I _{ZT}	I _{ZT}	Z _{ZT} @ I _{ZT}	Z _{ZK} @ I _{ZK}	I _{ZK}	Tc @	@ I _{ZT}	C _T @ f = 1MHz, V _R = 0V	I _R	@ V _R
		Min (V)	Max (V)	mA	2	2	mA	Min (mV/°C)	Max (mV/°C)	Max (pF)	μA	v
BZT52HC2V4WF	WX	2.2	2.6	5	85	400	1	-3.5	0.0	450	50	1
BZT52HC2V7WF	W1	2.5	2.9	5	83	500	1	-3.5	0.0	450	20	1
BZT52HC3V0WF	W2	2.8	3.2	5	95	500	1	-3.5	0.0	450	10	1
BZT52HC3V3WF	W3	3.1	3.5	5	95	500	1	-3.5	0.0	450	5	1
BZT52HC3V6WF	W4	3.4	3.8	5	95	500	1	-3.5	0.0	450	5	1
BZT52HC3V9WF	W5	3.7	4.1	5	95	500	1	-3.5	0.0	450	3	1
BZT52HC4V3WF	W6	4.0	4.6	5	95	500	1	-3.5	0.0	450	3	1
BZT52HC4V7WF	W7	4.4	5.0	5	78	500	1	-3.5	0.2	300	3	2
BZT52HC5V1WF	W8	4.8	5.4	5	60	480	1	-2.7	1.2	300	2	2
BZT52HC5V6WF	W9	5.2	6.0	5	40	400	1	-2.0	2.5	300	1	2
BZT52HC6V2WF	WA	5.8	6.6	5	10	150	1	0.4	3.7	200	3	4
BZT52HC6V8WF	WB	6.4	7.2	5	8	80	1	1.2	4.5	200	2	4
BZT52HC7V5WF	WC	7.0	7.9	5	10	80	1	2.5	5.3	150	1	5
BZT52HC8V2WF	WD	7.7	8.7	5	10	80	1	3.2	6.2	150	0.7	5
BZT52HC9V1WF	WE	8.5	9.6	5	10	100	1	3.8	7.0	150	0.5	6
BZT52HC10WF	WF	9.4	10.6	5	10	70	1	4.5	8.0	90	0.2	7
BZT52HC11WF	WG	10.4	11.6	5	10	70	1	5.4	9.0	85	0.1	8
BZT52HC12WF	WH	11.4	12.7	5	10	90	1	6.0	10.0	85	0.1	8
BZT52HC13WF	WI	12.4	14.1	5	10	110	1	7.0	11.0	80	0.1	8
BZT52HC15WF	WJ	13.8	15.6	5	15	110	1	9.2	13.0	75	0.05	10.5
BZT52HC16WF	WK	15.3	17.1	5	20	170	1	10.4	14.0	75	0.05	11.2
BZT52HC18WF	WL	16.8	19.1	5	20	170	1	12.4	16.0	70	0.05	12.6
BZT52HC20WF	WM	18.8	21.2	5	20	220	1	14.4	18.0	60	0.05	14.0
BZT52HC22WF	WN	20.8	23.3	5	25	220	1	16.4	-	60	0.05	15.4
BZT52HC24WF	WO	22.8	25.6	5	30	220	1	18.4	-	55	0.05	16.8
BZT52HC27WF	WP	25.1	28.9	2	40	250	1	21.4	-	50	0.05	18.9
BZT52HC30WF	WQ	28.0	32.0	2	40	250	1	24.4	-	50	0.05	21.0
BZT52HC33WF	WR	31.0	35.0	2	40	250	1	27.4	-	45	0.05	23.1
BZT52HC36WF	WS	34.0	38.0	2	60	250	1	30.4	-	45	0.05	25.2
BZT52HC39WF	WT	37.0	41.0	2	75	300	1	33.4	-	45	0.05	27.3
BZT52HC43WF	WU	40.0	46.0	2	80	325	1	37.6	-	40	0.05	30.1
BZT52HC47WF	WV	44.0	50.0	2	90	325	1	42.0	-	40	0.05	32.9

8. Short duration pulse test used to minimize self-heating effect. 9. f = 1kHz. Notes:

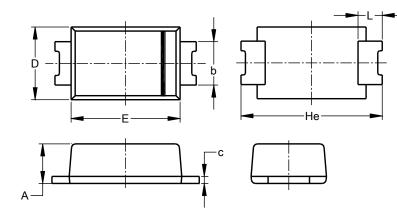


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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



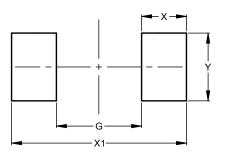
SOD123F (Type B)							
Dim	Min	Max	Тур				
Α	0.81	1.15	-				
b	0.80	1.35	-				
С	0.05	0.30	-				
D	1.70	1.90	1.80				
ш	2.60	2.80	2.70				
He	3.30	3.70	3.50				
L	0.35	0.85	-				
All	Dimen	sions	in mm				

BZT52HC2V4WF - BZT52HC47WF Document number: DS36891 Rev. 4 - 2



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Y	1.50

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